

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company



Bi-CMOSIC Low power consumption and high efficiency Step-down Switching Regulator

Overview

LV5990M is 1ch DC-DC converter with built-in power Pch MOS transistor. The recommended operating range is 4.5V to 18V. The maximum current is 3A. The operating current is about 90μ A, and low power consumption is achieved.

Functions

- 1ch SBD rectification DC-DC converter IC with built-in power Pch MOS transistor
- Maximum value of light load mode current is $90\mu A$.
- Built-in OCP circuit with P-by-P method
- When P-by-P is generated continuously, it shifts to the HICCUP operation.
- If connect C-HICCUP to GND pin, then latch-off when over current.
- The oscillatory frequency is 360kHz.
- UVLO and built-in TSD

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Input voltage	V _{IN} -max		22	V
Allowable pin voltage	SW		30	V
	EN, PG		∨ _{IN}	V
	PDR		V _{IN} -6	V
	REF		6	V
	SS,FB,COMP C-HICCUP		REF	V
Allowable power dissipation	Pd max	specified substrate *	1.05	W
Operating temperature	Topr		-40 to 85	°C
Storage temperature	Tstg		-55 to 150	°C

* Specified board: 40.0mm \times 30.0mm \times 1.6mm, glass epoxy.

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LV5990M

Recommended Operating Conditions at $Ta = 25^{\circ}C$

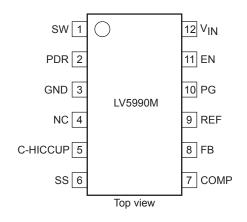
Parameter	Symbol	Conditions	Ratings	Unit
Input voltage renge	V _{IN}		4.5 to 18	V

Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{IN} = 15V$

Parameter	Symbol	Conditions	Ratings			Unit
- didifictor	Cymbol	Conditions	min	typ	max	Onit
Reference voltage						
Internal reference voltage	VREF		1.235	1.260	1.285	V
Pch drive voltage	VPDR	I _{OUT} =0 to -5mA	V _{CC} -5.5	V _{CC} -5.0	V _{CC} -4.5	V
Saw wave oscillator						
Oscillatory frequency	Fosc		300	360	420	kHz
ON/OFF circuit						
IC startup voltage (EN pin)	V _{CNT_} ON		1.5		V _{IN}	V
Disable voltage (EN pin)	V _{CNT_} OFF				0.3	V
Soft start circuit	•					
Soft start source current	I _{SS} _SC	EN>1.5V	1.3	2	3	μA
Soft start sink current	I _{SS} _SK	EN<0.3V, SS=0.4V	120	150	180	μA
UVLO circuit		·	· ·	1		
UVLO release voltage	V _{UVLO} N	FB=COMP	3.0	3.4	3.8	V
UVLO lock voltage	VUVLOF	FB=COMP	2.5	2.9	3.3	V
Error amplifier	1			1		
Input bias current	I _{EA} _IN		-100	-50	100	nA
Error amplifier gain	G _{EA}		100	250	400	μ Α /
Output sink current	I _{EA_} OSK	FB=1.75V	-40	-20	-10	μA
Output source current	I _{EA_} OSC	FB=0.75V	10	20	40	μA
Over current limit circuit						
Current limit peak	ICL		3.2	4.7	6.2	Α
HICCUP timer start-up cycle	NLCYCLES			15		cycl
HICCUP comparator threshold voltage	VtHIC		1.20	1.26	1.32	V
HICCUP timer charge current	IHIC		1	2	3	μA
PWM comparator		I				
Maximum on-duty	D _{MAX}		95			%
Logic output	W/ V	I				
Power good "L" sink current	lpwrgd_L	PG=5V	4	5	6	mA
Power good "H" leakage current	Ipwrgd_H	PG=5V			1	μA
Power good threshold FB voltage	V _{tPG}		1.0	1.1	1.2	V
Power good hysteresis	V _{PG} _H		40	50	60	m∖
Power good impedance	R _{PG}			1		kΩ
Output	1 10	1	1			L
Output on-resistance	R _{ON}	I _O =1A		150		mΩ
The entire device		- -	1			L
Standby current	ICCS	EN<0.3V			1	μA
Light load mode consumption current	Isleep1	EN>1.5V, I _{LOAD} =0, No oscillatory -20°C≤Ta≤70°C *	50	70	90	μA
Thermal shutdown	TSD	*		170		°C

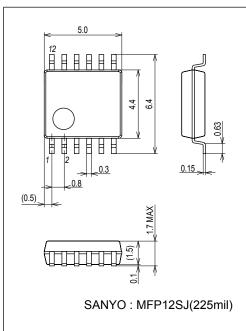
*: Design certification

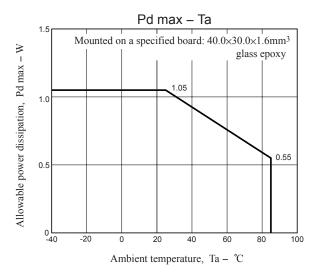
Pin Assignment



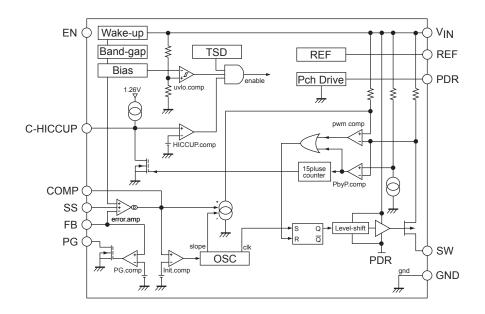
Package Dimensions

unit : mm (typ) 3403

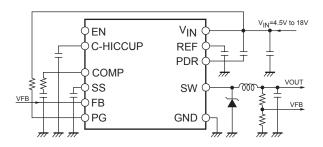




Block Diagram



Application Circuit



Pin F	unction		
Pin No.	Pin name	Function	Equivalent circuit
1	SW	High-side Pch MOSFET drain pin	······· ≶ 30mΩ ······- F SW
2	PDR	Pch MOSFET gate drive voltage The bypass capacitor is necessarily connected between this pin and V _{IN} .	$1.3M\Omega \lesssim$ $1.5M\Omega \lesssim$ $10k\Omega \lesssim$ $10k\Omega \lesssim$ $10\Omega \lesssim$ GND
3	GND	Ground pin.	
12	VIN	Ground pin voltage is reference voltage. Supply voltage pin. It is observed by the UVLO function. When its voltage becomes	GND
5	C-HICCUP	3.4V or more. ICs startup in soft start. It is capacitor connection pin for setting re-startup cycle in HICCUP mode. If connect it to GND pin, then latch-off when over current.	
6	SS	Capacitor connection pin for soft start. About 2µA current charges the soft start capacitor.	V_{IN}
7	COMP	Error amplifier output pin. The phase compensation network is connected between GND pin and COMP pin.	
8	FB	Error amplifier reverse input pin. ICs make its voltage keep 1.26V. Output voltage is divided by external resistances and it across FB.	VIN FB 10kΩ 1kΩ 1kΩ 1kΩ 1kΩ 1kΩ

Continued on next page.

Pin No.	Pin name	Function	Equivalent circuit
9	REF	Reference voltage	$\begin{array}{c} V_{\text{IN}} & 10\Omega \\ 10\Omega \\ 10\Omega \\ 51k\Omega \\ 51k\Omega \\ 10\Omega \\ 10\Omega$
10	PG	Power good pin. Connect to open drain of MOS-FET in ICs inside. Setting output voltage to "L", when FB voltage is 1.05V or less.	PG ↓ \$1kΩ GND
11	EN	ON/OFF pin.	VIN EN GND

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